



Screen Printable Fire Through Nickel Contacts for Crystalline Silicon Solar Cell

Veysel Unsur, Ph.D.^{1,2}

¹ Necmettin Erbakan University, Konya, Turkiye

² ODTU-GUNAM, Middle East Technical University, Ankara Turkiye



ODTÜ GÜNAM
CENTER FOR SOLAR ENERGY RESEARCH AND APPLICATIONS



**NECMETTIN
ERBAKAN
UNIVERSITY**

Outline

- **Motivation**
- **Approach**
 - Paste Preparation
 - Wafer Preparation
 - Printing
- **Results**
 - Electrical Performance
 - Microstructural Analysis
- **Future Work and Conclusion**

Motivation: Why is Ag problematic?

The total supply of Ag demand is about to lack meeting the demand!

Environmental impact of Ag is greater than the alternatives.

Alternatives such as nickel are evenly distributed around.

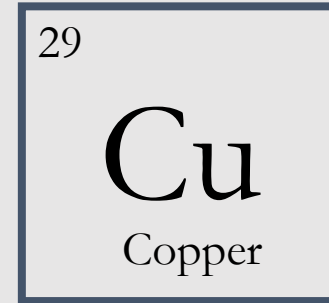
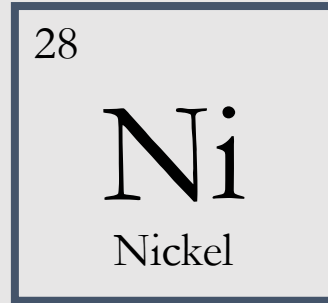
Silver Supply/Demand Summary [1]					
	2012	2016	2020	2022	2030
Total Supply (MOz)	1,008	1,046.9	953.0	1,030.3	1075.6
Electrical and Electronics	270.9	308.9	304.1	353.3	435.7
Total Industrial	445.2	475.3	464.9	539.6	628.5
Jewellery/Bar/Coin	439.9	400.4	354.8	481.0	524.2
Photovoltaics	55.0	93.7	101.0	127.0	251.2
Total Demand	978.8	979.4	880	1,101.8	1252.2
Price (per ounce)		\$17.17	\$20.69	\$21.76	\$80-\$120

3

[1] The Silver Institute

[2] Metal Focus

Motivation: What are the alternatives?



Price (per kg)	\$24	\$8	\$808
Conductivity (S/m)	14.9×10^6	59.6×10^6	62.1×10^6
Metal work function (eV)	5.02 – 5.43	4.64 - 4.82	4.69 - 4.85
Adhesion	Best	Good	Good
Environmental impact	Low	Medium	High

4

Motivation: Why Ni over Cu?

Ni has higher resistance to **oxidation** compared to Cu

Ni has higher resistance to **humidity (corrosion)** compared to Cu

Ni has better **adhesion** to Si than Cu

Ni has **no diffusion** into Si during high temperatures like Cu

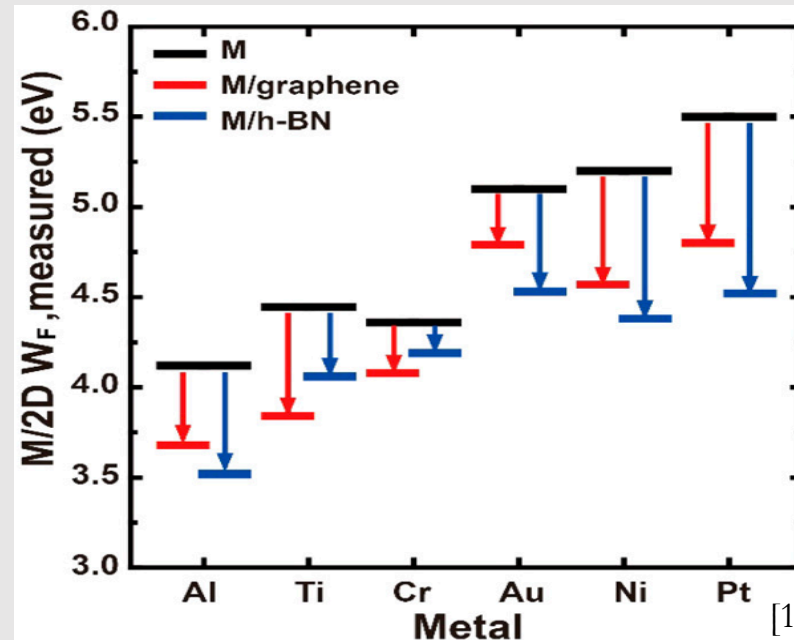
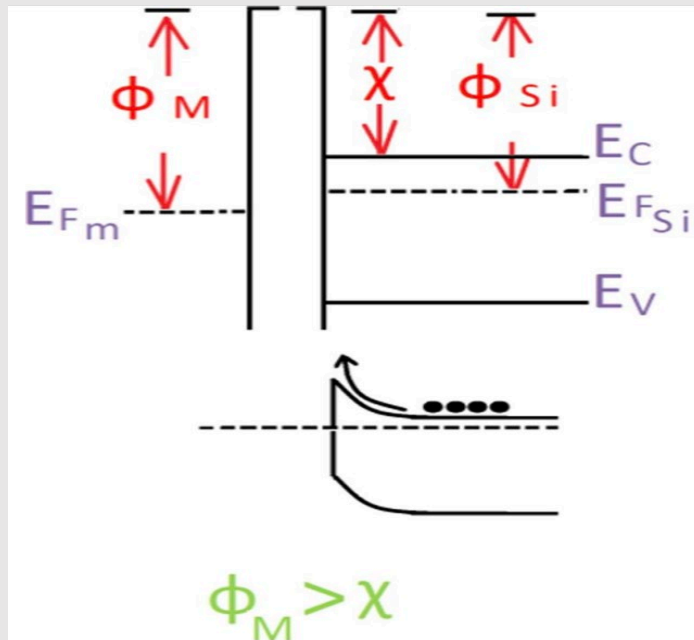
5

Approach: Requirements for a Ni based contacts

1- Good ohmic contact formation

- Ni has a work function of over 5 eV
- c-Si has the electron affinity of 4.05eV

- To avoid Schottky contact formation, the metal work function is tuned

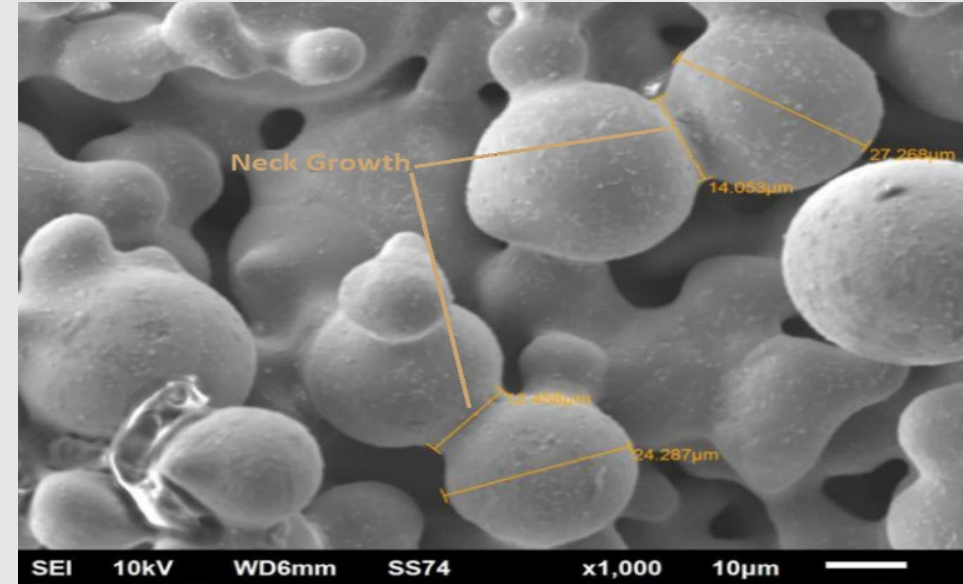
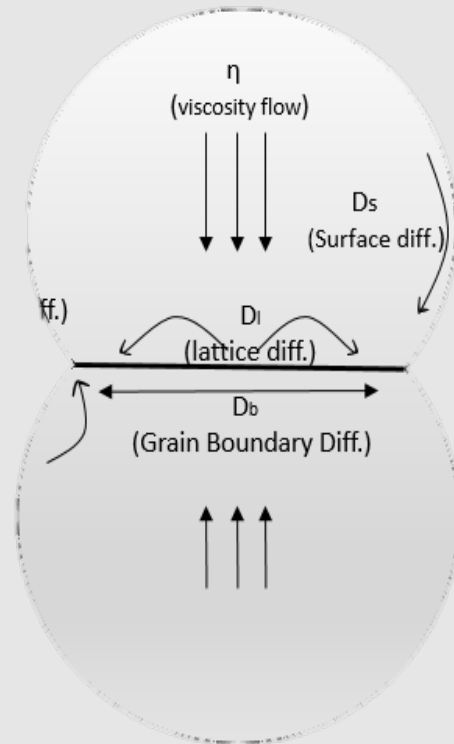
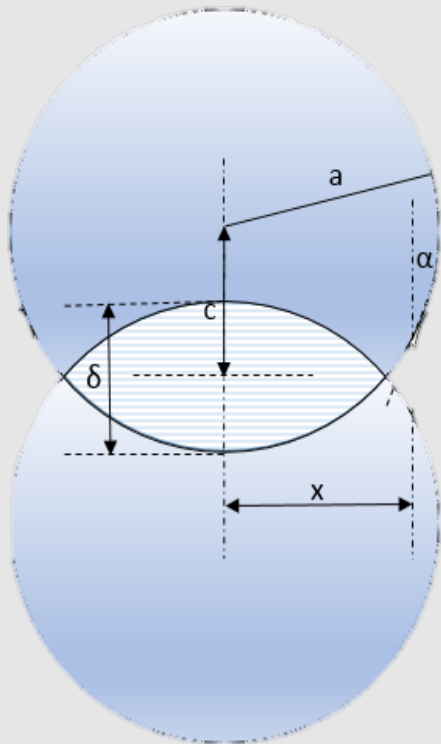


- There's a flow of electrons from 2D material to the metal that lowers the metal work function

[1] Nano Lett. 2018, 18, 8, 4878–4884

Approach: Requirements for a Ni based contacts

2- Low series resistance - finger resistance - sintering



$$\Delta V \propto \frac{t \cdot T}{r^3}$$

$r \uparrow \rightarrow \Delta V \downarrow \downarrow \downarrow$

$t \uparrow \rightarrow \Delta V \uparrow$

$T \uparrow \rightarrow \Delta V \uparrow$

ΔV : shrinkage volume
 r : radius of Ag particles
 t : time
 T : temperature
 D_v : diffusion coefficient

Approach: Requirements for a Ni based contacts

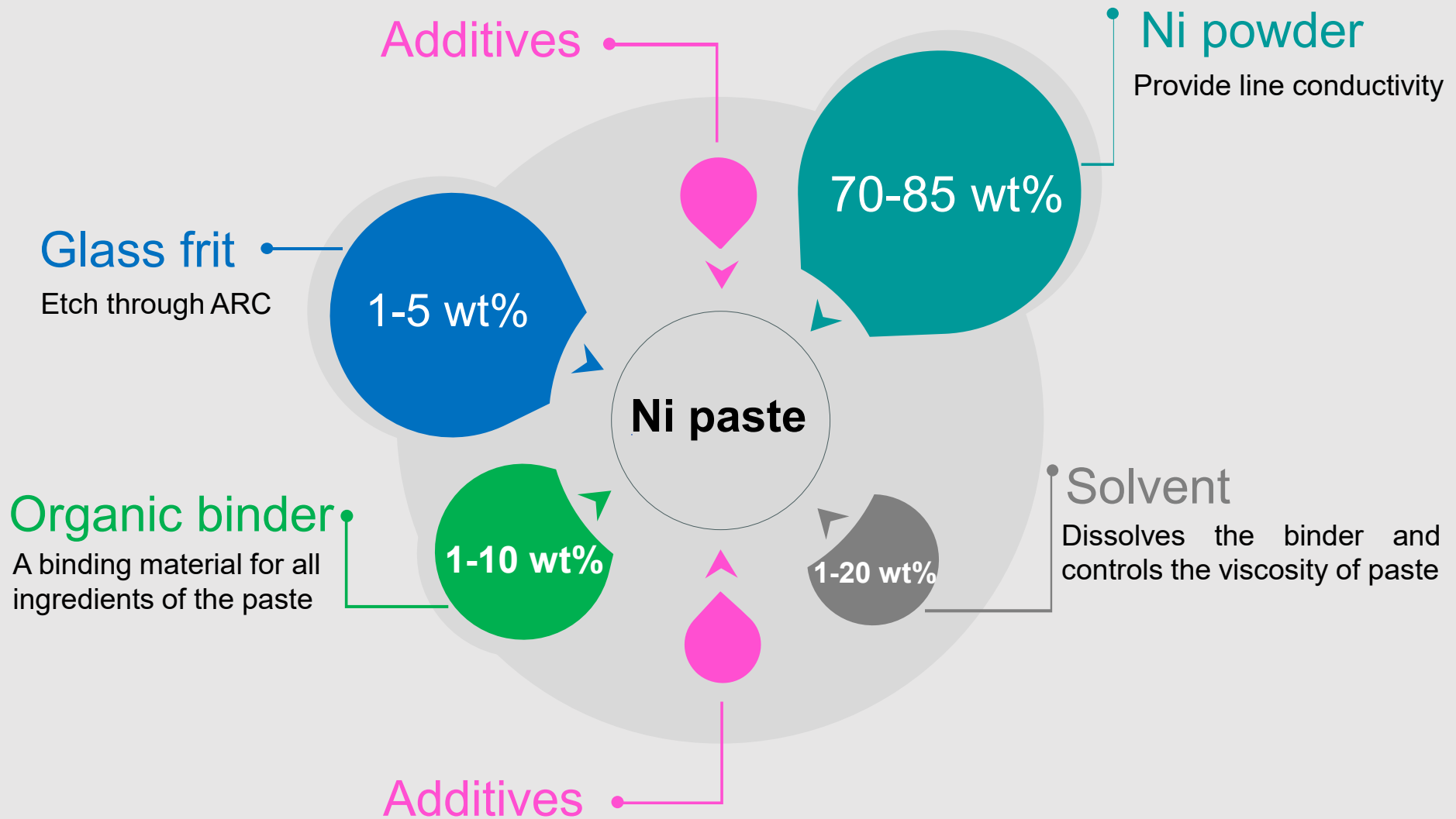
3- Low diffusivity into Si

- Ni atom clusters are bigger than Cu which doesn't allow moving through interstitial sites in the Si lattice
- Ni has moderate solubility in Si compared to Cu that has high solubility
- The binding energy between Ni and Si is stronger than Cu/Si

4- Adhesion

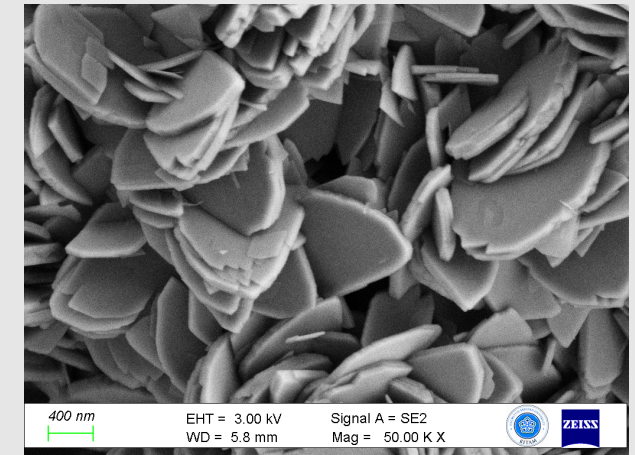
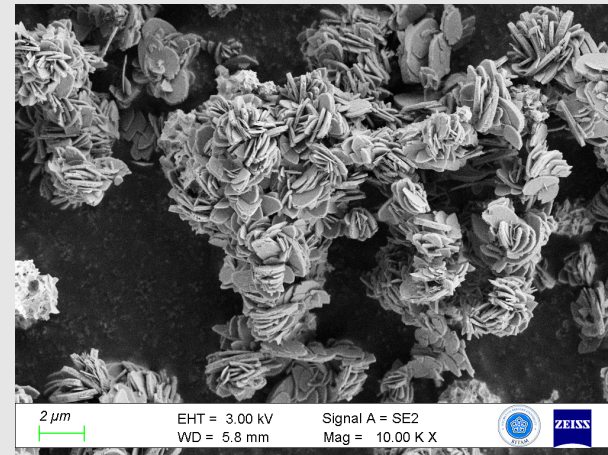
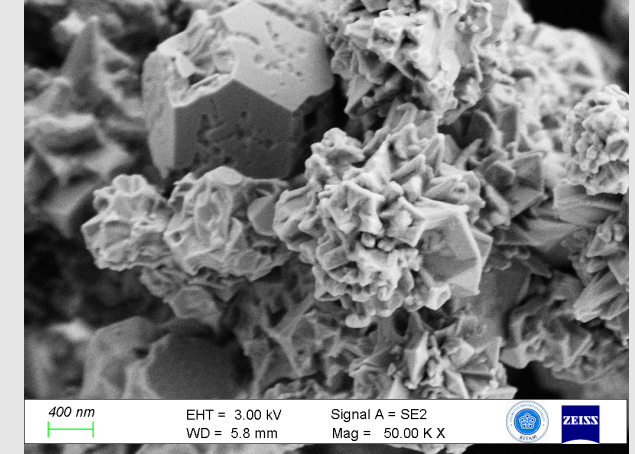
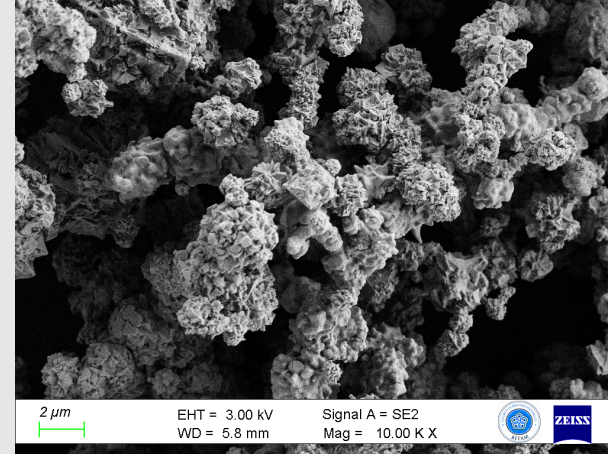
- Relatively strong binding energy between Ni and Si provides good adhesion

Approach: Paste Preparation



Approach: Metal Powder

- The metal particle size is below $1\mu\text{m}$
- To increase the surface energy of the Ni particles, the surface is treated



Ni Powder

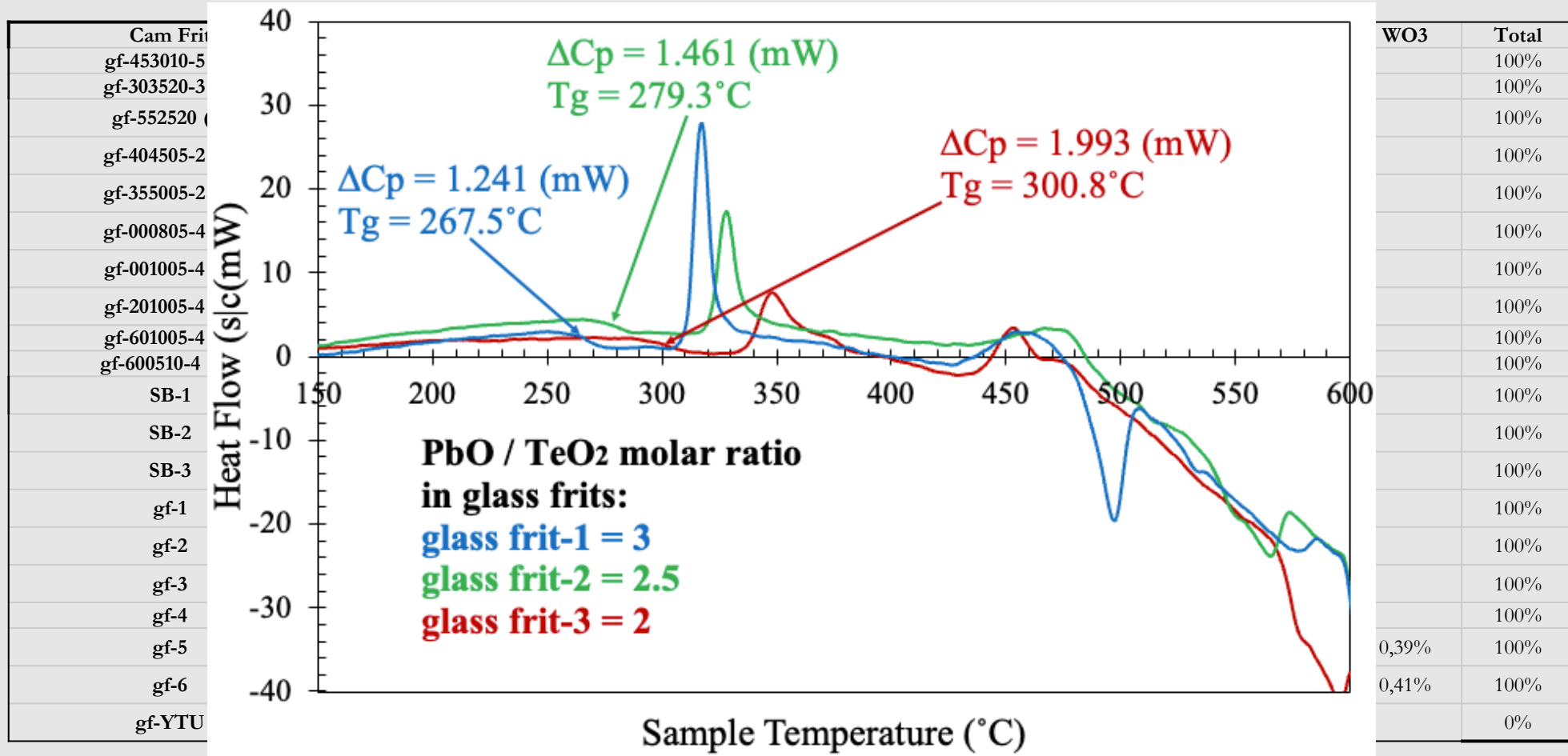
Surface treated Ni

	Diameter at 10.00 %	Diameter at 50.00 %	Diameter at 90.00 %
Min.	0.112	0.463	1.402
Max	0.113	0.470	1.425
Mean	0.112	0.466	1.414
Standard deviation	0.001	0.004	0.011
CV	0.511	0.758	0.806
	0.113	0.470	1.425
	0.112	0.466	1.414
	0.112	0.463	1.402

Approach: Glass Frit

Cam Frit	Tg	PbO	SiO2	Al2O3	TeO2	B2O3	Bi2O3	ZnO	MgO	WO3	Total
gf-453010-5 (1)		45%	30%	10%	5%	3%	3%	2%	2%		100%
gf-303520-3 (2)		30%	35%	20%	5%	5%	5%				100%
gf-552520 (3)	215,42 C	55%	25%	20%							100%
gf-404505-2 (4)	216,96 C	40%	45%	5%		6%		4%			100%
gf-355005-2 (5)	223,11 C	35%	50%	5%		6%		4%			100%
gf-000805-4 (6)	215,52 C		8%	5%	40%	6%	33%	8%			100%
gf-001005-4 (7)	189,1 C		10%	5%	45%	10%	25%	5%			100%
gf-201005-4 (8)	174,81 C	20%	10%	5%	25%	10%	25%	5%			100%
gf-601005-4 (9)		60%	10%	5%	10%	5%	5%	5%			100%
gf-600510-4 (10)		60%	5%	10%	5%	5%	10%	5%			100%
SB-1	300,8 C	40%	5%		20%	10%	15%	10%			100%
SB-2	279,34 C	50%			20%	10%	10%	10%			100%
SB-3	267,54 C	60%			20%	10%		10%			100%
gf-1	279,29 C	60%	10%	5%	10%	5%	5%	5%			100%
gf-2	258,30 C	60%	5%	10%	5%	5%	10%	5%			100%
gf-3	241,73 C		2%	2%	5%	20%	35%	36%			100%
gf-4					65%		15%	20%			100%
gf-5	268,61 C	24,34%	15,07%	0,89%	45,39%		8,36%	5,56%		0,39%	100%
gf-6	284,86 C	25,28%	15,66%	0,92%	41,25%		10,70%	5,78%		0,41%	100%
gf-YTU	273,97 C										0%

Approach: Glass Frit



12

- The resistance of the glass frit is in the range of $10^{-8} \Omega \cdot \text{cm}$ at room temperature!

Approach: Organic Vehicle

For the Organic vehicle:

- As solvents: Terpeneol, Texanol and Butyl Butyrate
- As binders: Ethyl Cellulose or PVP
- As thixotropic agents: Castor Oil or Polyamide Wax
- As surfactants: Sorbitan Triolate

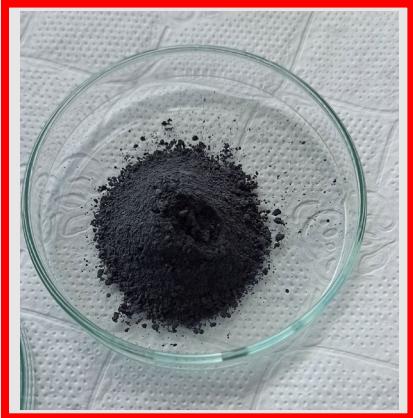


DVNXRVTJG 2.1.8.3-9										VISCOSITY DATA REPORT				17/01/23			
SAMPLE RUN INFORMATION					Test End: 17/01/23 16:35			Tester: Administrator		Model: DVNXRVTJG		SRC: 0.000		FWV: 2.1.8.3-9		YMC: 0.000	
Test Start: 17/01/23 16:35					S/N: 86036486			SMC: 100.000		Temperature Control: No		Temperature Offset: None		Test Data Saved: 17/01/23 16:36		Accessory: None	
Instrument: RV (1.000000)					S/N: 0			Temperature Control: No		Temperature Offset: None		Test Data Saved: 17/01/23 16:36		Accessory: None		Test Data Saved by: Administrator	
Spindle RV-06 (6)					Global Limits: None			File: Internal Memory/17.01/50 RPM Spindle 6.vdt		Notes: None							
Test Method										Test Method Saved On:				Test Method Created By:			
Test Method File Name: Unsaved Test										Instructions:							
Step (#)	Speed (RPM)	Temperature (°C)	Data Collection Type	Data Interval (hh:mm:ss)	Avg Duration (hh:mm:ss)	Collect point at step end	End Condition Type Oper. Val. Tol Unit	Density (g/cm³)	QC Limits Type Low High Unit								
1	5.0	25.0	Single Point	OFF	OFF	OFF	Time = 00:00:30 OFF s	0.0000	None								
Results																	
Test Averaging:																	
Step	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)									
0	0.00	0.0	0.00	---	---	---	0.0000	0.00									
Step Averaging:																	
Step	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)									
1	60800	30.4	5.0	---	---	23.2	0.0000	2000									
Gel Time (mm:ss)			Total Time (mm:ss)		Peak Temp (°C)		Peak Temp Time (mm:ss)										
00:00:00.0			00:00:30.0		0.0 °C		00:00:00.0										
DATA																	
Step (#)	Point (#)	Time (s)	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)							
1	1	30.4	60800	30.4	5.0	---	---	23.2	0.0000	2000							
DVNXRVTJG 2.1.8.3-9										VISCOSITY DATA REPORT				17/01/23			
SAMPLE RUN INFORMATION					Test End: 17/01/23 16:42			Tester: Administrator		Model: DVNXRVTJG		SRC: 0.000		FWV: 2.1.8.3-9		YMC: 0.000	
Test Start: 17/01/23 16:41					S/N: 86036486			SMC: 400.000		Temperature Control: No		Temperature Offset: None		Test Data Saved: 17/01/23 16:42		Accessory: None	
Instrument: RV (1.000000)					S/N: 0			Temperature Control: No		Temperature Offset: None		Test Data Saved: 17/01/23 16:42		Accessory: None		Test Data Saved by: Administrator	
Spindle RV-07 (7)					Global Limits: None			File: Internal Memory/17.01/50 RPM Spindle 7.vdt		Notes: None							
Test Method										Test Method Saved On:				Test Method Created By:			
Test Method File Name: Unsaved Test										Instructions:							
Step (#)	Speed (RPM)	Temperature (°C)	Data Collection Type	Data Interval (hh:mm:ss)	Avg Duration (hh:mm:ss)	Collect point at step end	End Condition Type Oper. Val. Tol Unit	Density (g/cm³)	QC Limits Type Low High Unit								
1	50.0	25.0	Single Point	OFF	OFF	OFF	Time = 00:00:30 OFF s	0.0000	None								
Results																	
Test Averaging:																	
Step	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)									
0	0.00	0.0	0.00	---	---	---	0.0000	0.00									
Step Averaging:																	
Step	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)									
1	49280	61.6	50.0	---	---	23.1	0.0000	800.0									
Gel Time (mm:ss)			Total Time (mm:ss)		Peak Temp (°C)		Peak Temp Time (mm:ss)										
00:00:00.0			00:00:30.0		0.0 °C		00:00:00.0										
DATA																	
Step (#)	Point (#)	Time (s)	Viscosity (cP)	Torque (%)	Speed (RPM)	Shear Stress (dyne/cm²)	Shear Rate (1/s)	Temperature (°C)	Density (g/cm³)	Accuracy (+/-cP)							
1	1	30	49280	61.6	50.0	---	---	23.1	0.0000	800.0							

5.5 < Thixotropic index < 9.0

13

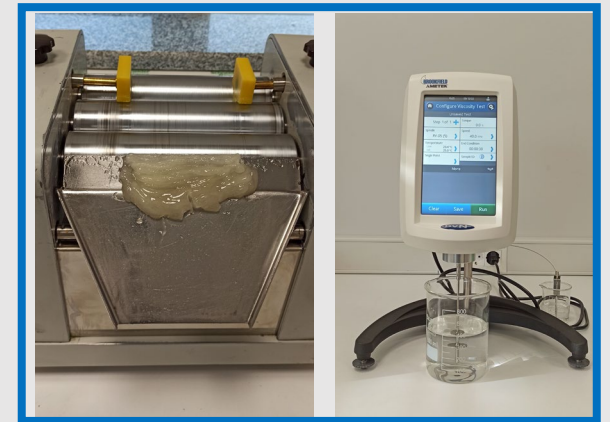
Approach: Metal Paste



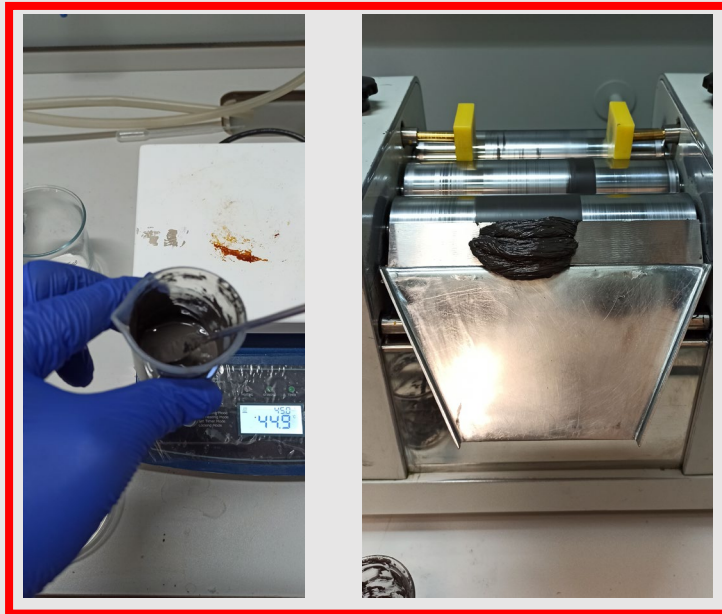
metal particles



glass frit



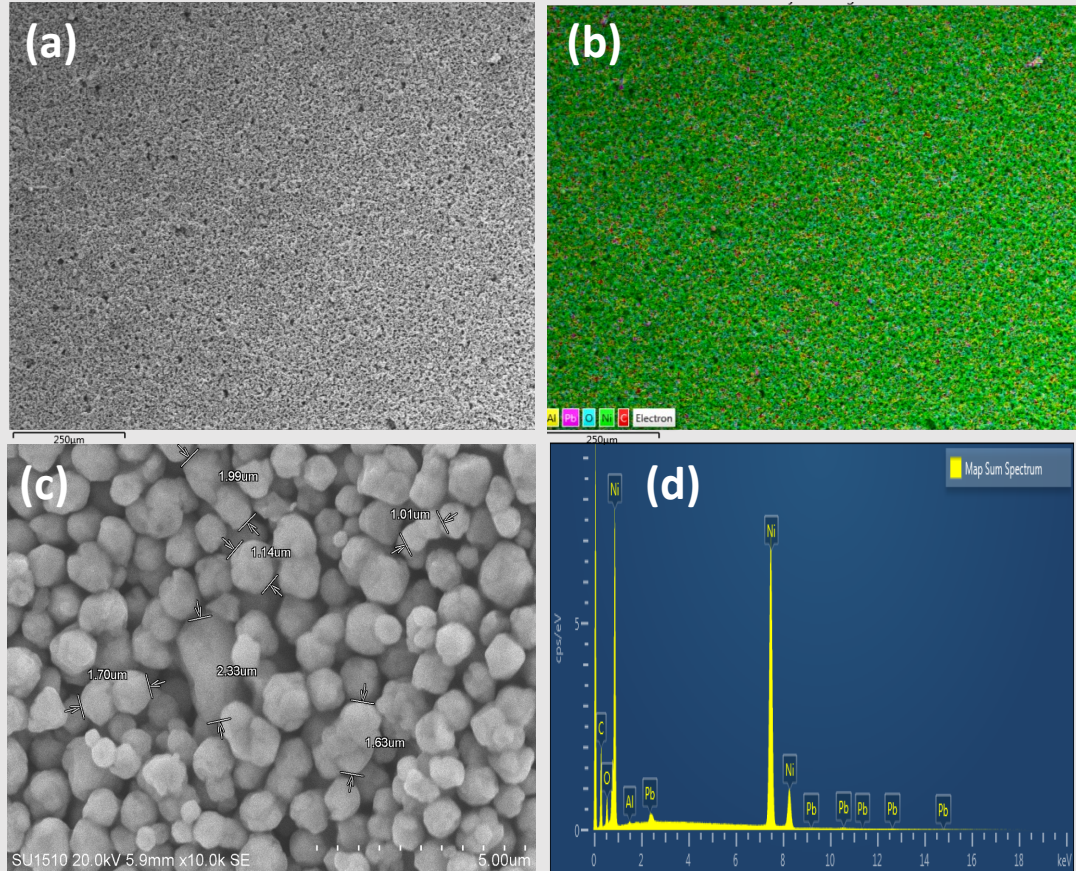
organic vehicle



Metal Paste

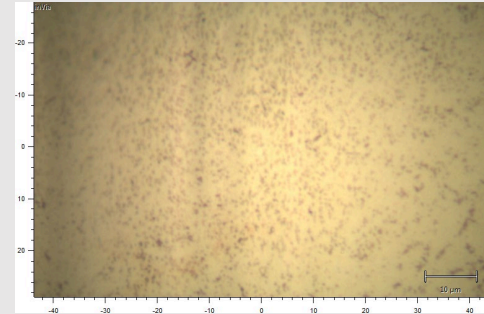
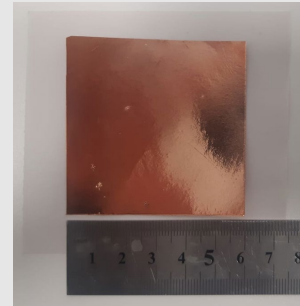
Approach: Metal Paste

- All the prepared components:
Metal Powder
Glass Frit
Organic Vehicle
are then three roll milled

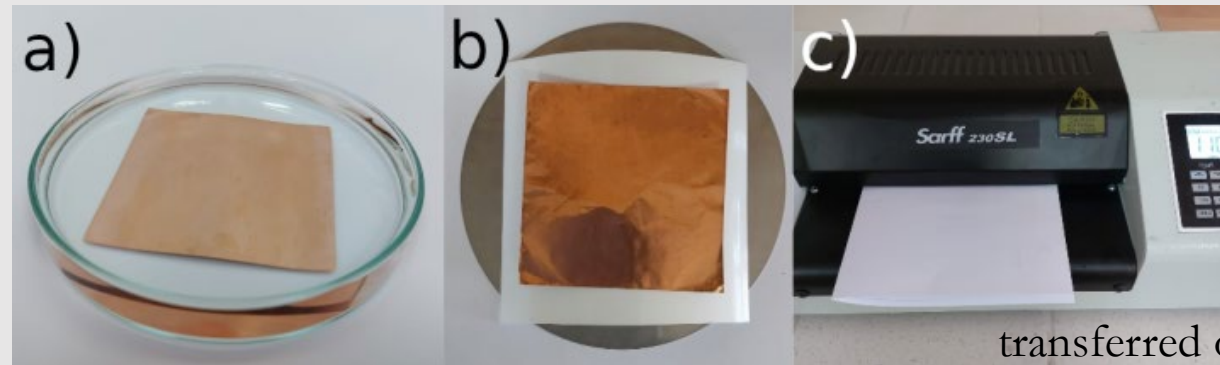


Approach: Graphene

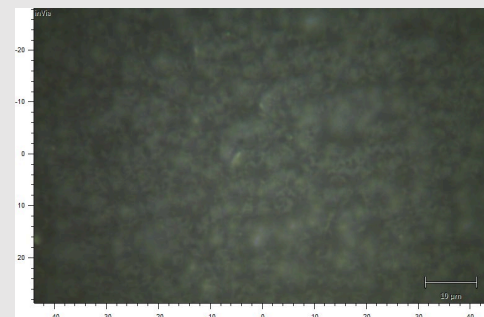
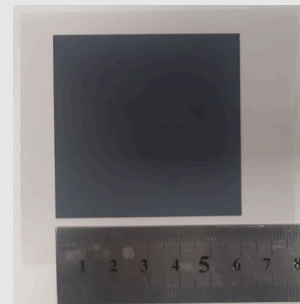
- Graphene is grown on a copper foil
- Then it is transferred via a simple laminator on the wafer
- Optical images show somehow evenly distribution of graphene



on a copper foil

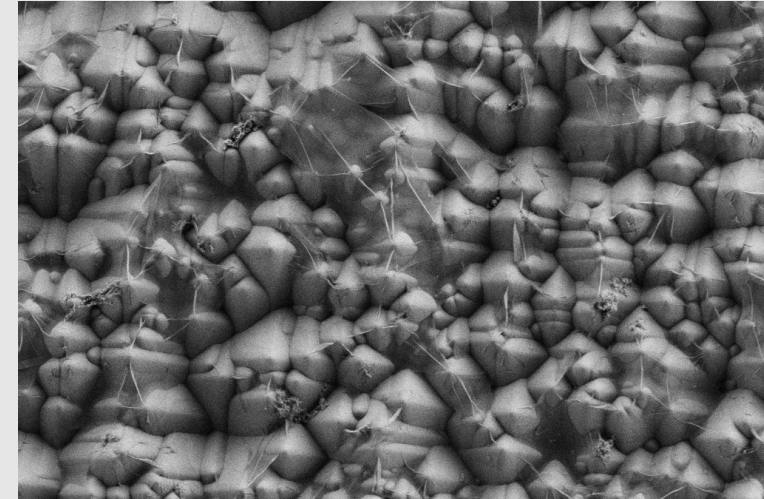
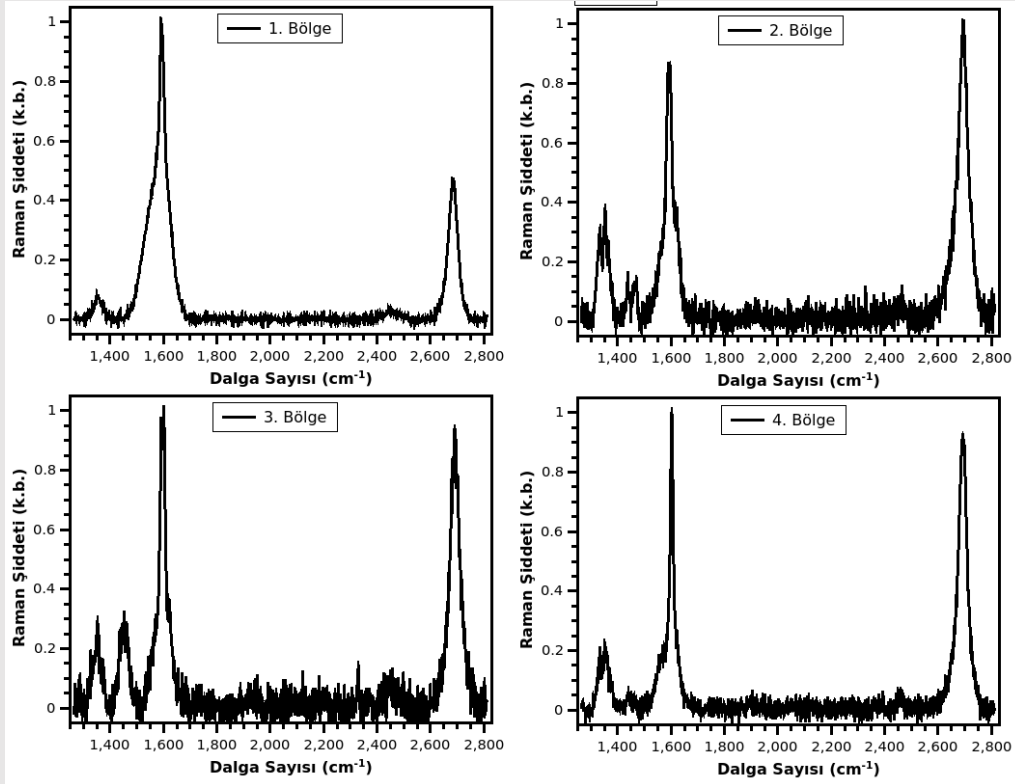


transferred onto acetate

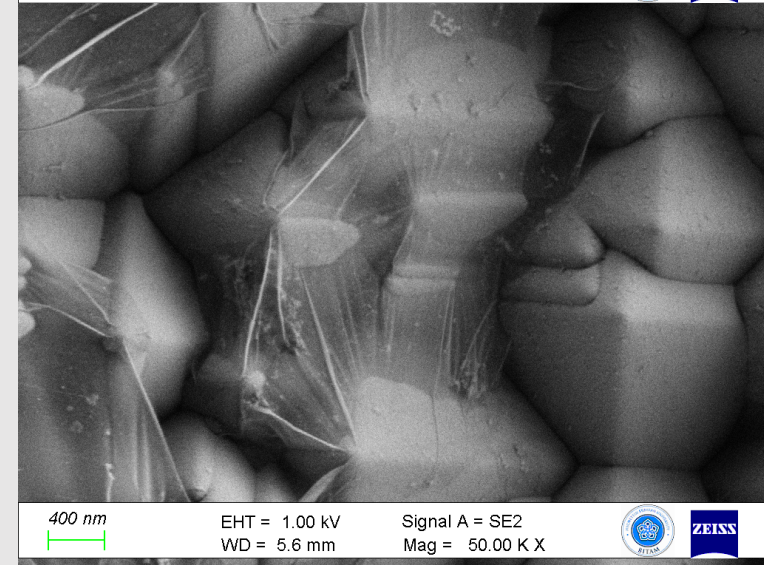


transferred onto the wafer

Approach: Graphene



1 µm EHT = 1.00 kV Signal A = SE2
WD = 6.2 mm Mag = 20.00 K X

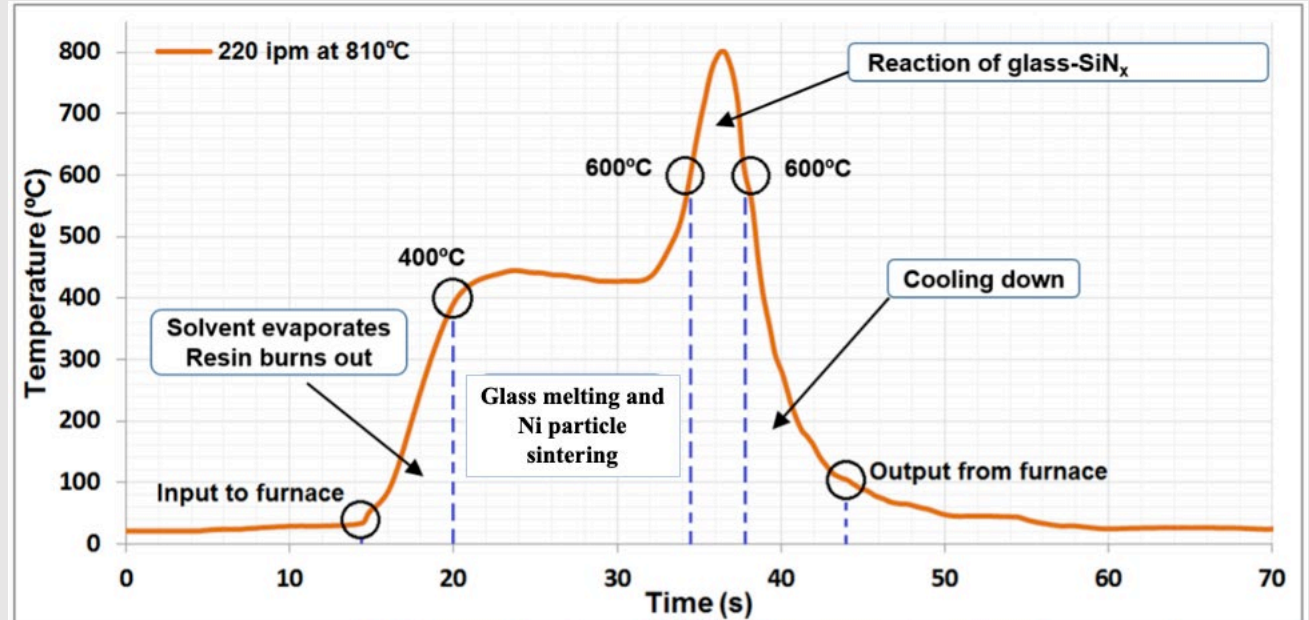


400 nm EHT = 1.00 kV Signal A = SE2
WD = 5.6 mm Mag = 50.00 K X



Approach: Screen Printing and Firing

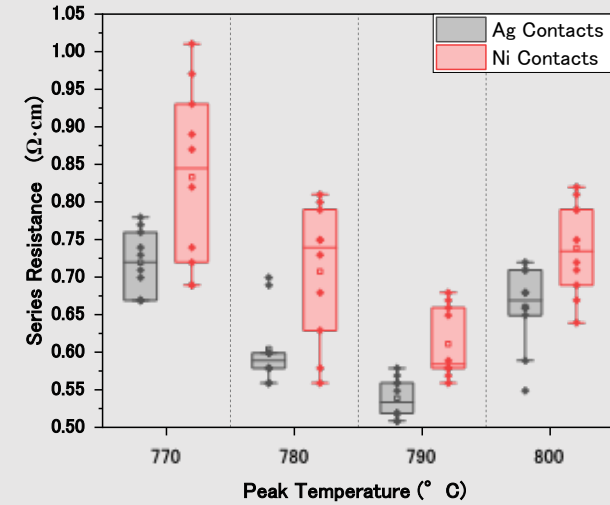
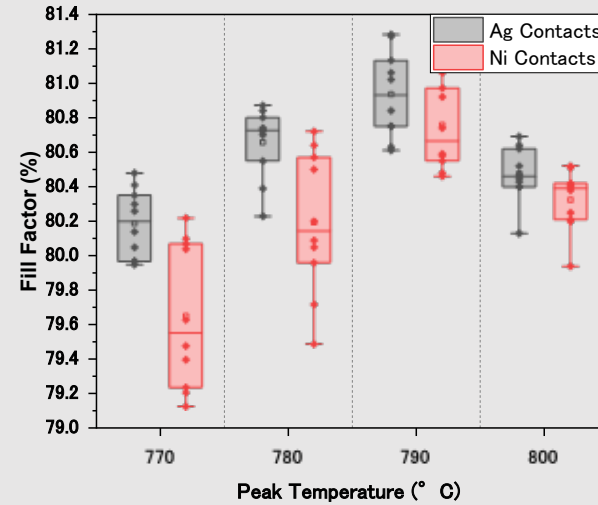
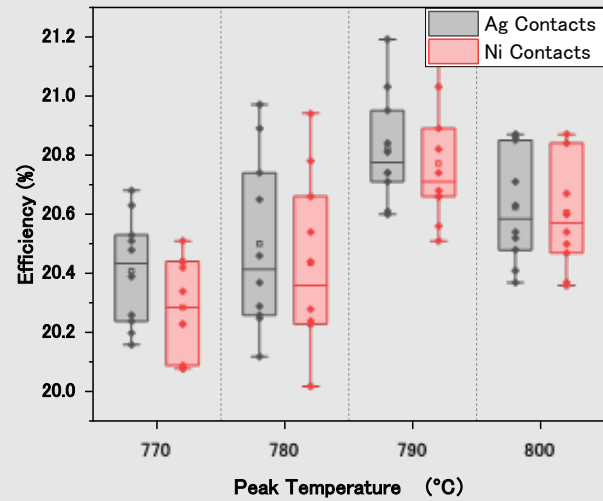
- The metal pastes then printed onto the wafer with the graphene layer on top
- The cell are finally fired with the similar temperature profile



		Maximum Temperature	Maximum Positive Slope	Maximum Negative Slope	Time Between Temperature	Time Above Temperature: Rising (+)	Time Above Temperature: Falling (+)	Time Above Temperature: Total (+/-)
		°C	°C/sec	°C/sec	390-430°C	600°C	600°C	600°C
<input type="checkbox"/>	Show All				sec	sec	sec	sec
<input checked="" type="checkbox"/>	A2 Sensor 2 Location	801.7	127.83	-190.04	1.6	1.9	1.4	3.4
	Range	0.0	0.00	0.00	0.0	0.0	0.0	0.0
	Average	801.70	127.830	-190.040	1.60	1.90	1.40	3.40
	Std Deviation	-1.#IO	-1.#IND	-1.#IND	-1.#IO	-1.#IO	-1.#IO	-1.#IO
Template: C:\ECD\MegamoleMAP\Template\DataTableCalculations.tpf								

Results

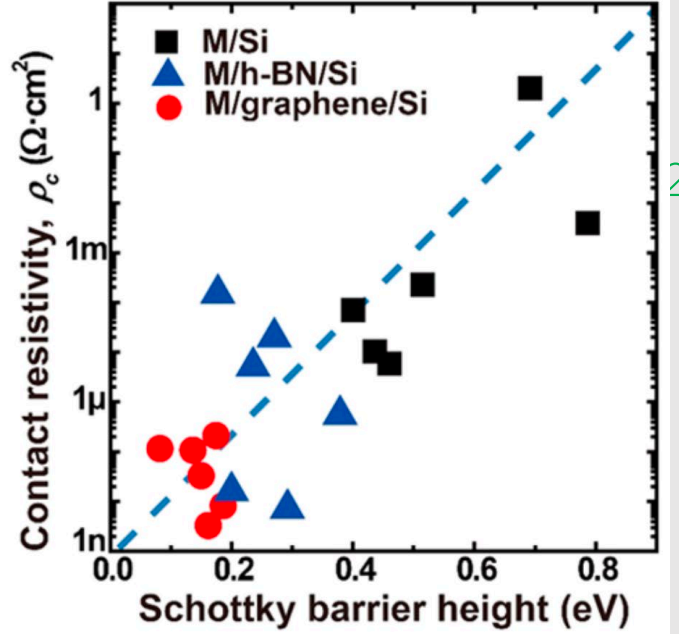
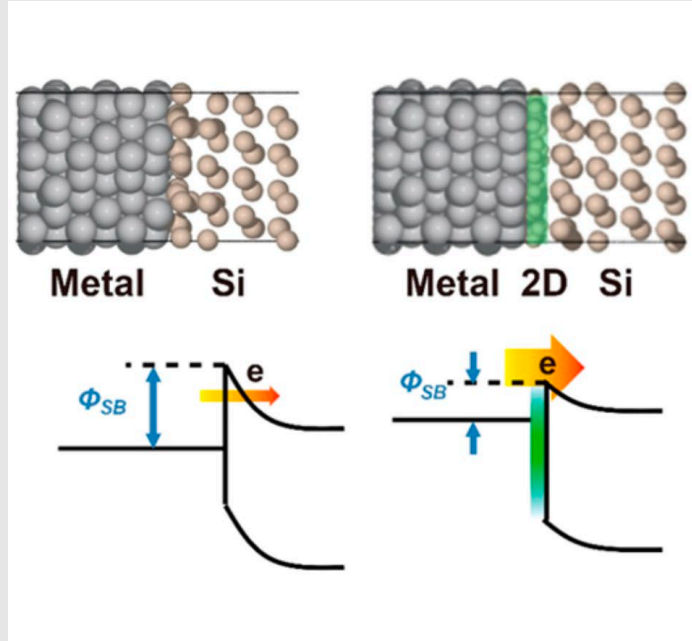
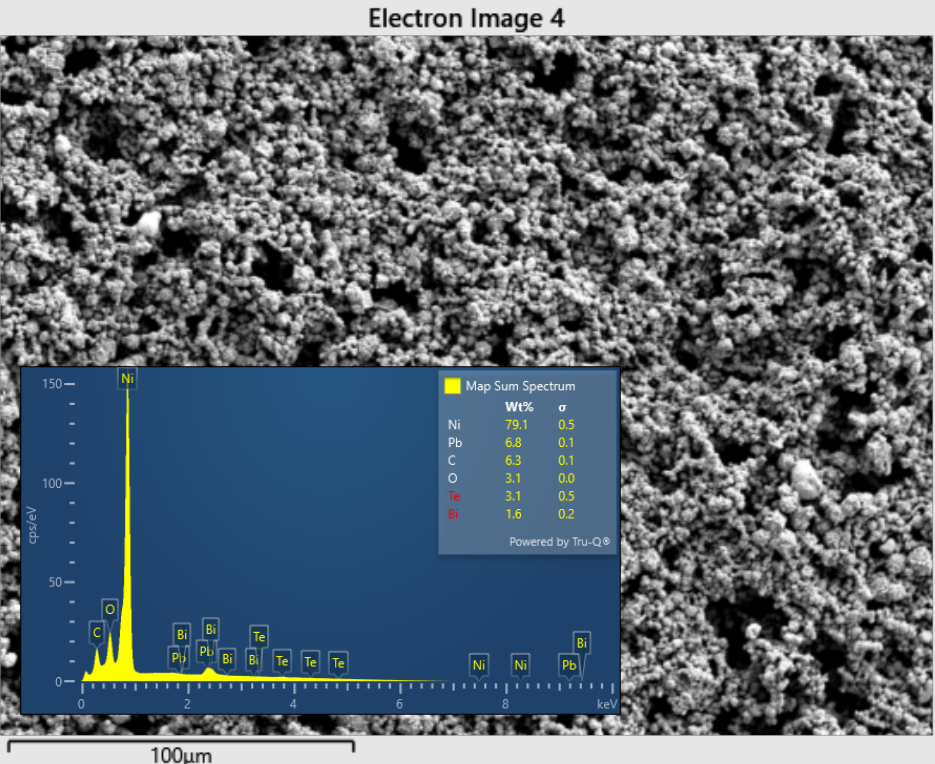
Electrical Measurement



- The mean lateral finger resistance for the Ni contacts is $1.1\Omega/\text{cm}$ while the Ag contacts yielded $1\Omega/\text{cm}$.
- The mean contact resistance for the Ni contacts is $5.2\text{ m}\Omega\cdot\text{cm}^2$ while the Ag counterpart is $4.8\text{ m}\Omega\cdot\text{cm}^2$

Results

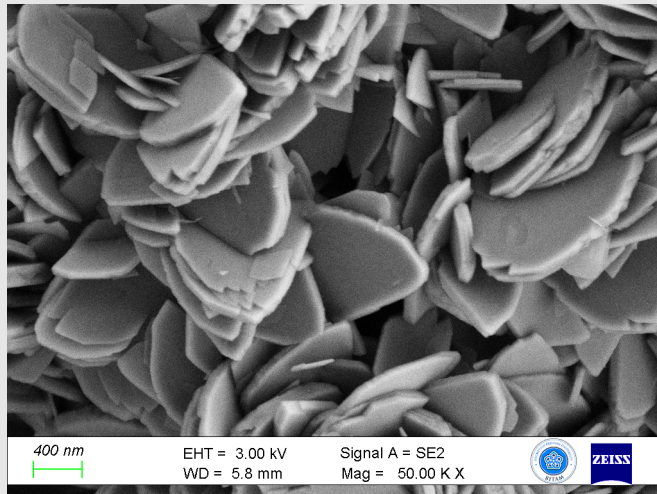
Microstructure analysis



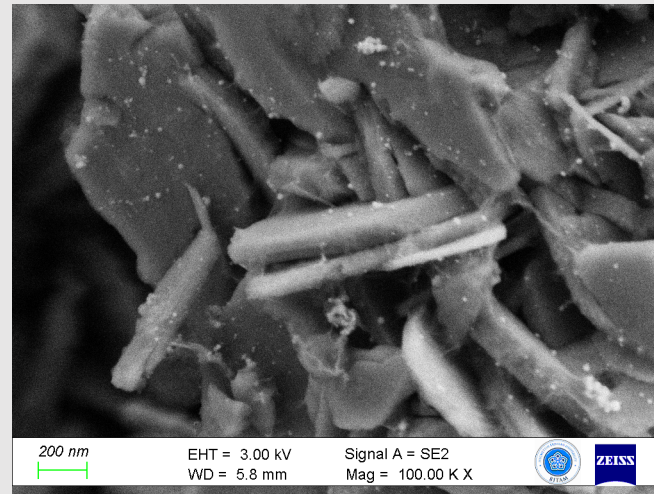
20

Future Work and Conclusion

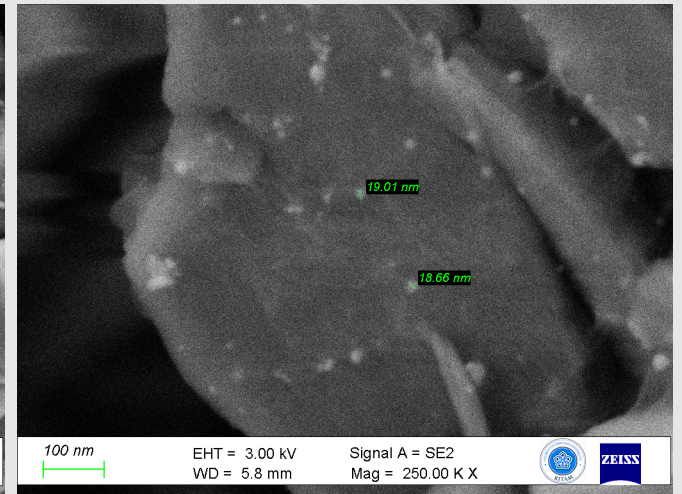
- This study is a proof of work on screen printable Ni contacts.
- The challenge is to have the graphene layer transferred onto the Si before metallization.
- To avoid this, doping the graphene onto Ni powder creates the same effect on the metal work function



Surface treated Ni



Surface treated Ni with doped powder





Thank you for your attention!

Questions?

Veysel Unsur, Ph.D.^{1,2}



ODTÜ GÜNAM
CENTER FOR SOLAR ENERGY RESEARCH AND APPLICATIONS



**NECMETTİN
ERBAKAN
UNIVERSITY**